

ALD1110EPAL

ALD1110EPAL Information

www.ener.com	 ALD1110EPAL Advanced Linear Devices Inc. Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CH 10V 8DIP 8-DIP (0.300", 7.62mm) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



ALD1110EPAL Specifications

Manufacturer Part Number	ALD1110EPAL
Manufacturer	Advanced Linear Devices Inc.
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-DIP (0.300", 7.62mm)
Series	EPAD?
FET Type	2 N-Channel (Dual) Matched Pair
FET Feature	Standard
Drain to Source Voltage (Vdss)	10V
Current - Continuous Drain (Id) @ 25°C	-
Rds On (Max) @ Id, Vgs	500 Ohm @ 5V
Vgs(th) (Max) @ Id	1.01V @ 1µA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	2.5pF @ 5V
Power - Max	600mW
Operating Temperature	0°C ~ 70°C (TJ)
Mounting Type	Through Hole
Package / Case	8-DIP (0.300", 7.62mm)
Supplier Device Package	8-PDIP
	Report errors?

ALD1110EPAL Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

ALD1110EPAL Payment Methods



ALD1110EPAL Shipping Methods



If you have any question about ALD1110EPAL, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com